

APTM120H57FT3G

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APTM120H57FT3G Information

Cital Investmenter	Part Number	APTM120H57FT3G
	Manufacturer	Microsemi Corporation
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays
	Description	MOSFET 4N-CH 1200V 17A SP3
	Package	SP3
		For the pricing/inventory/lead time, please contact
For Reference Only		us
		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



APTM120H57FT3G Specifications

Manufacturer Part Number	APTM120H57FT3G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SP3
Series	-
FET Type	4 N-Channel (H-Bridge)
FET Feature	Standard
Drain to Source Voltage (Vdss)	1200V (1.2kV)
Current - Continuous Drain (Id) @ 25°C	17A
Rds On (Max) @ Id, Vgs	684 mOhm @ 8.5A, 10V
Vgs(th) (Max) @ Id	5V @ 2.5mA
Gate Charge (Qg) (Max) @ Vgs	187nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	5155pF @ 25V
Power - Max	390W
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	SP3
Supplier Device Package	SP3
	Report errors?

APTM120H57FT3G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM120H57FT3G Payment Methods





If you have any question about APTM120H57FT3G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com